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PATENT TRADEMARK OFFICE

CHAPTER II

TRANSMITTAL LETTER TO THE UNITED STATES ELECTED OFFICE (EO/US) (ENTRY INTO U.S. NATIONAL PHASE UNDER CHAPTER II)

INTERNATIONAL APPLICATION NO.		INT	ERNATIONAL FI	LING DATE	PRIORITY DATE CI	AIMED
PCT/JP2005/002495		17	FEBRUARY	2005	18 FEBRUARY	2004
TITLE OF INVENTION						
ORGANIC THIN-FIL	M TRANSISTOR	AN	ID FABRICATI	ON METHOI	THEREOF AND	ORGANIC
THIN-FILM DEVICE					······································	
APPLICANT(S)						
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Mail Ston BCT						

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ATTENTION: EO/US

INFORMATION DISCLOSURE STATEMENT

We draw the attention of the Examiner to the attached non-English-language

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* Only the date of filing (§ 1.6) will be the date used in a patent term adjustment calculation, although the date on any certificate of mailing or transmission under § 1.8 continues to be taken into account in determining timeliness. See § 1.703(f). Consider "Express Mail Post Office to Addressee" (§ 1.10) or facsimile transmission (§ 1.6(d) for the reply

EXPRESS MAIL LARE corded the earliest possible filing date for patent term adjustment calculations.

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version of a Search Report from a foreign in respect of counterpart International Application No. PCT/JP2005/002495 and an English-language version thereof that indicates the degree of relevance found by the foreign office. The Search Report makes consideration of any non-English art required. MPEP 609.

Form PTO-1449 is also attached with reference copies.

Respectfully submitted,

WILLIAM R. EVANS LADAS & PARRY LLP 26 WEST 61ST STREET NEW YORK, N.Y. 10023

REG.NO.25,858(212)708-1930

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(Use several sheets if necessary)					FILING DATE			GROUP			
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EXAMINER INITIALS	REFERENCE DESIGNATION	DOCUMENT NUMBER	DAT	E NAME			FILING DATE IF APPROPRIATE				
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	ОТІ	HER ART (Including	ng Author, T	itle, Date,	, Pertinent Dates, Etc.)					
	AN	Sakamoto, Y. et al. "Perfluorinated Oligothiophenes and Pentacene as n-Type Semiconductors for Organic Filed-Effect Transistors" <i>Proc. MRS Fall Meeting</i> (2003) K10.52									
	AO	Gundlach, D.J. et al. "Thin-Film Transistors Based on Well-Ordered Thermally Evaporated Naphthacene Films" <i>Applied Physics Letters</i> (2002) Vol. 80, No. 16, pp 2925-2927									
	AP	Malenfant, P. et al. "N-type Organic Thin-film Transistor with High Field-effect Mobility Based on a N,n'-dialkyl-3,4,9,10-perylene Tetracarboxylic Diimide Derivative" <i>Applied Physics Letters</i> (2002) Vol. 80, No. 14, pp 2517-2519									
	AQ	Katz, H.E. et al. "A Soluble and Air-Stable Organic Semiconductor with High Electron Mobility" Nature (2000) Vol. 404, pp 478-480									
	AR	Bao, Z. et al. "New Air-Stable n-Channel Organic Thin Film Transistors" J. Am. Chem. Soc. (1998) Vol. 120, No. 1, pp 207-208									
	AS	Lin, Y.Y. et al. "Stacked Pentacene Layer Organic Thin-Film Transistors with Improved Characteristics" <i>IEEE Electron Device Letters</i> (1997) Vol. 18, No. 12, pp 606-608									
EXAMINER		DATE CONSIDERED									
EXAMINER:	Initial if citation considered, whether or not citation is in conformance with MPEP 609; Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.										